



#### HIGH GAIN NPN MEDIUM POWER TRANSISTOR IN SOT23

#### **Feature**

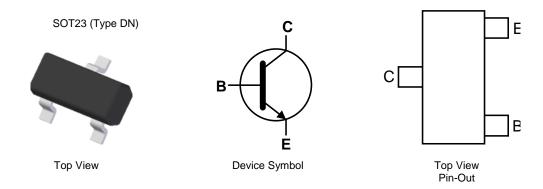
- BV<sub>CEO</sub> > 60V
- I<sub>C</sub> = 1A Continuous Collector Current
- V<sub>CE(SAT)</sub>= 0.5V @1A
- 500mW Power Dissipation
- Low Saturation Voltage
- High h<sub>FE</sub> Min 300@250mA
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 <sup>®</sup>
- Weight: 0.008 grams (Approximate)

# **Applications**

- Various Driving Functions Including Motors, Actuators, Solenoid and Relays
- · Backlight Inverters
- DC-DC Modules



# Ordering Information (Note 4)

| Part Number | Compliance | Marking | Reel Size (inches) | Tape Width (mm) | Quantity per Reel |
|-------------|------------|---------|--------------------|-----------------|-------------------|
| FMMT493ATA  | AEC-Q101   | 93A     | 7                  | 8               | 3,000             |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**

93A

SOT23 (Type DN)

93A = Product Type Marking Code



#### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic               | Symbol           | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage       | V <sub>CBO</sub> | 120   | V    |
| Collector-Emitter Voltage    | V <sub>CEO</sub> | 60    | V    |
| Emitter-Base Voltage         | V <sub>EBO</sub> | 7     | V    |
| Continuous Collector Current | Ic               | 1     | Α    |
| Peak Pulse Current           | I <sub>CM</sub>  | 2     | Α    |
| Base Current                 | I <sub>B</sub>   | 200   | mA   |

#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                                   | Symbol          | Value       | Unit |
|--|-----------------|-------------|------|
| Power Dissipation (Note 5)                       | P <sub>D</sub>  | 500         | mW   |
| Thermal Resistance, Junction to Ambient (Note 5) | $R_{\theta JA}$ | 250         | °C/W |
| Thermal Resistance, Junction to Lead (Note 6)    | $R_{	heta JL}$  | 197         | °C/W |
| Operating and Storage Temperature Range          | $T_{J,}T_{STG}$ | -55 to +150 | °C   |

# ESD Ratings (Note 7)

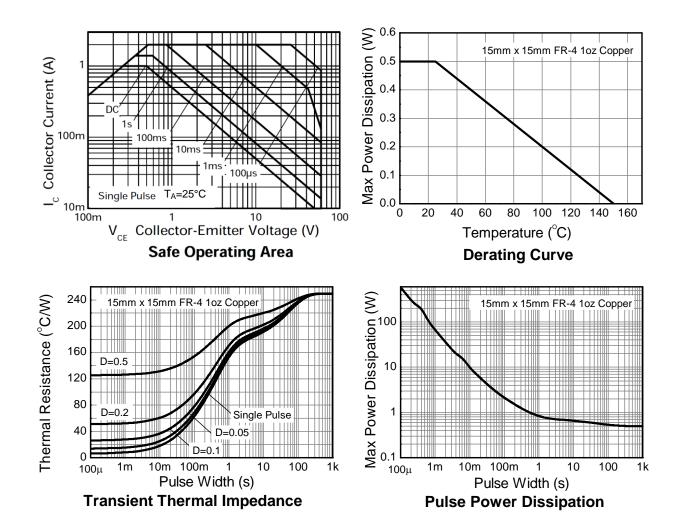
| Characteristic                             | Symbol  | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V    | 3A          |
| Electrostatic Discharge - Machine Model    | ESD MM  | ≥ 400 | V    | С           |

Notes:

- 5. For a device surface mounted on 15mm x 15mm FR-4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
- 6. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# **Thermal Characteristics and Derating Information**





# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

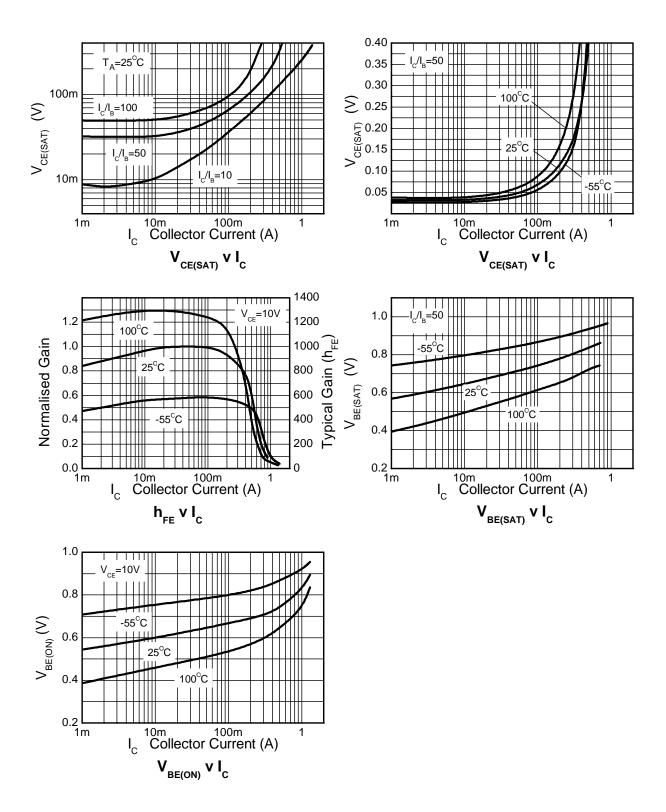
| Characteristic                                 | Symbol               | Min | Тур | Max  | Unit | Test Condition                              |
|--|----------------------|-----|-----|------|------|---|
| Collector-Base Breakdown Voltage               | $BV_CBO$             | 120 | _   | _    | V    | $I_{C} = 100 \mu A$                         |
| Collector-Emitter Breakdown Voltage (Note 8)   | $BV_CEO$             | 60  | _   | _    | V    | $I_C = 10mA$                                |
| Emitter-Base Breakdown Voltage                 | BV <sub>EBO</sub>    | 7   | _   | _    | V    | $I_{E} = 100 \mu A$                         |
| Collector Cutoff Current                       | I <sub>CBO</sub>     | _   |     | 100  | nA   | $V_{CB} = 45V$                              |
| Emitter Cutoff Current                         | I <sub>EBO</sub>     | _   | _   | 100  | nA   | $V_{EB} = 4V$                               |
| Collector Emitter Cutoff Current               | I <sub>CES</sub>     | _   |     | 100  | nA   | V <sub>CE</sub> = 45V                       |
|  | h <sub>FE</sub>      | 300 | _   | _    |      | $I_C = 1mA$ , $V_{CE} = 10V$                |
|  |                      | 500 | _   | _    |      | $I_C = 150 \text{mA}, V_{CE} = 10 \text{V}$ |
| Static Forward Current Transfer Ratio (Note 8) |                      | 300 |     | 1200 |      | $I_C = 250 \text{mA}, V_{CE} = 10 \text{V}$ |
|  |                      | 100 | _   | _    |      | $I_C = 500 \text{mA}, V_{CE} = 10 \text{V}$ |
|  |                      | 20  | _   | _    |      | $I_C = 1A$ , $V_{CE} = 10V$                 |
| Collector-Emitter Saturation Voltage (Note 8)  | V <sub>CE(SAT)</sub> | _   | _   | 250  | mV   | $I_C = 500 \text{mA}, I_B = 50 \text{mA}$   |
| Collector-Emitter Saturation Voltage (Note 8)  |                      | _   | _   | 500  |      | $I_C = 1A$ , $I_B = 100mA$                  |
| Base-Emitter Turn-On Voltage (Note 8)          | $V_{BE(ON)}$         | _   | _   | 1.0  | V    | $I_C = 1A, V_{CE} = 10V$                    |
| Base-Emitter Saturation Voltage (Note 8)       | $V_{BE(SAT)}$        | _   | _   | 1.15 | V    | $I_C = 1A$ , $I_B = 100mA$                  |
| Output Capacitance                             | $C_obo$              | _   | _   | 10   | pF   | $V_{CB} = 10V, f = 1MHz$                    |
| Transition Frequency                           | f⊤                   | 150 | _   | _    | MHz  | $V_{CE} = 10V, I_{C} = 50mA,$<br>f = 100MHz |

Note:

8. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.



# Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

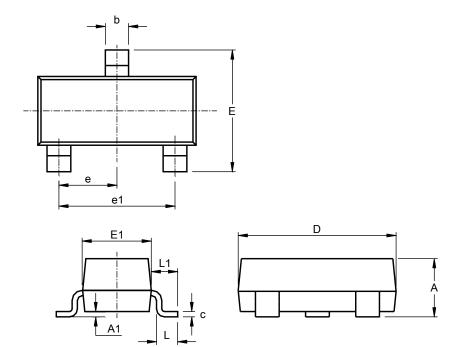




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23 (Type DN)

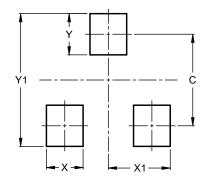


| SOT23 (Type DN)      |          |      |      |  |  |
|----------------------|----------|------|------|--|--|
| Dim                  | Min      | Max  | Тур  |  |  |
| Α                    | 0.89     | 1.12 | 1.00 |  |  |
| A1                   | 0.01     | 0.10 | 0.05 |  |  |
| b                    | 0.30     | 0.51 | 0.45 |  |  |
| С                    | 0.08     | 0.20 | 0.10 |  |  |
| D                    | 2.80     | 3.04 | 3.00 |  |  |
| ш                    | 2.10     | 2.64 | 2.42 |  |  |
| E1                   | 1.20     | 1.40 | 1.37 |  |  |
| е                    | 0.95 REF |      |      |  |  |
| e1                   | 1.90 REF |      |      |  |  |
| L                    | 0.25     | 0.60 | 0.30 |  |  |
| L1                   | 0.45     | 0.62 | 0.54 |  |  |
| All Dimensions in mm |          |      |      |  |  |

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23 (Type DN)



| Dimensions | Value (in mm) |  |  |
|------------|---------------|--|--|
| С          | 2.0           |  |  |
| Х          | 0.8           |  |  |
| X1         | 1.35          |  |  |
| Υ          | 0.9           |  |  |
| Y1         | 2.9           |  |  |



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